

Would >50 MV/m be Possible with Superconducting RF Cavities ?

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Outline



Nb1.3 GHz 9-cell cavity to be used for European XFEL

- **Background / motivation**
- **An innovative idea to increase the accelerator gradient using thin film superconductors**
- **Results of H_{c1} measurements using SQUID magnetometry at LANL**
- **Results of RF surface resistance and quench field measurements at SLAC**
- **Discussion of issues**
- **Conclusion**

While experimental results at LANL and SLAC are mostly discussed in this talk, a lot of people have been involved in this study. **Many thanks to them!!**

■ LANL

- Nestor Haberkorn and Leonardo Civale (**MPA-STC**): DC magnetization measurements,
- Ray DePaula and Isaiah Apodaca (MPA-STC): Alumina coatings
- Roland Schulze and his student (**MST-6**): AES/XPS analyses
- Dave Devlin (**MST-7**): discussions on cavity coating techniques.
- Marilyn Hawley (**MST-8**): AFM analyses and discussions

■ External collaborations

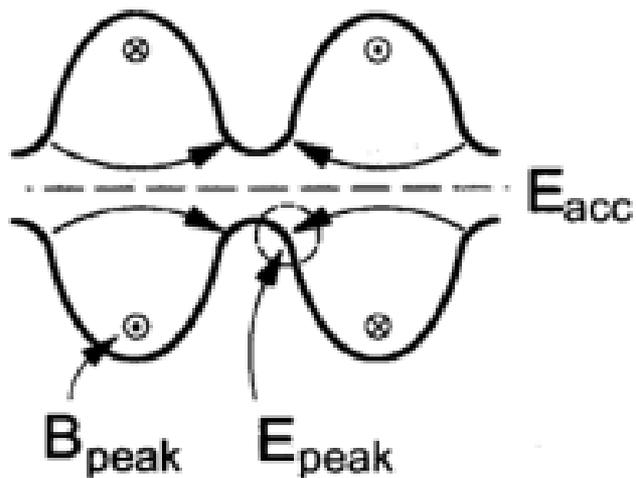
- Jiquan Guo, Sami Tantawi and their co-workers (**SLAC**): high-power RF testing at SLAC
- Thomas Proslie and Mike Pellin (**ANL**): some ALD coatings
- Brian Moeckly and Chris Yung (**STI**): preparation of MgB₂ samples using reactive co-evaporation technique
- Peter Kneisel, Grigory Ereemeev, Binping Xiao (**Jlab**): providing Nb materials and R_s measurements
- Akiyoshi Matsumoto, Hideki Abe and Minoru Tachiki (**NIMS**, Tsukuba, Japan): discussions
- Eiichiro Watanabe, Daiju Tsuya and Hirotaka Ohsato (NIMS, Tsukuba, Japan): ALD of alumina layers
- Toshiya Doi, Takafumi Nishikawa, Tomoaki Nagamine and Kazuki Yoshihara (**Kagoshima University, Japan**): preparation of some MgB₂ samples using E-beam co-evaporation technique
- Hitoshi Inoue (**KEK, Tsukuba, Japan**): vacuum baking of some Nb samples for coating

Background / motivation

- Niobium (Nb) Superconducting RF (SRF) cavities have been replacing Cu cavities for the last ~30 years due to better energy efficiency and other benefits.
- The highest accelerating gradient (E_{acc}) of existing accelerators as user facilities is ~ 20 MV/m.
- In the last few years, the technology to achieve >35 MV/m with 1.3 GHz 9–cell cavities has been maturing
- **But**, it is doubtful that we can get >50 MV/m SRF cavities in a practical sense using Nb technology (a traveling wave structure might have a chance, but it will not be discussed in this talk.)

What sets the fundamental limit of Nb SRF cavities?

- The fundamental limit that prevents niobium cavities from reaching >50 MV/m is the thermodynamic critical magnetic field of Nb, $H_c \cong 2000$ Oe ($B_c \cong \mu_0 H_c = 200$ mT)



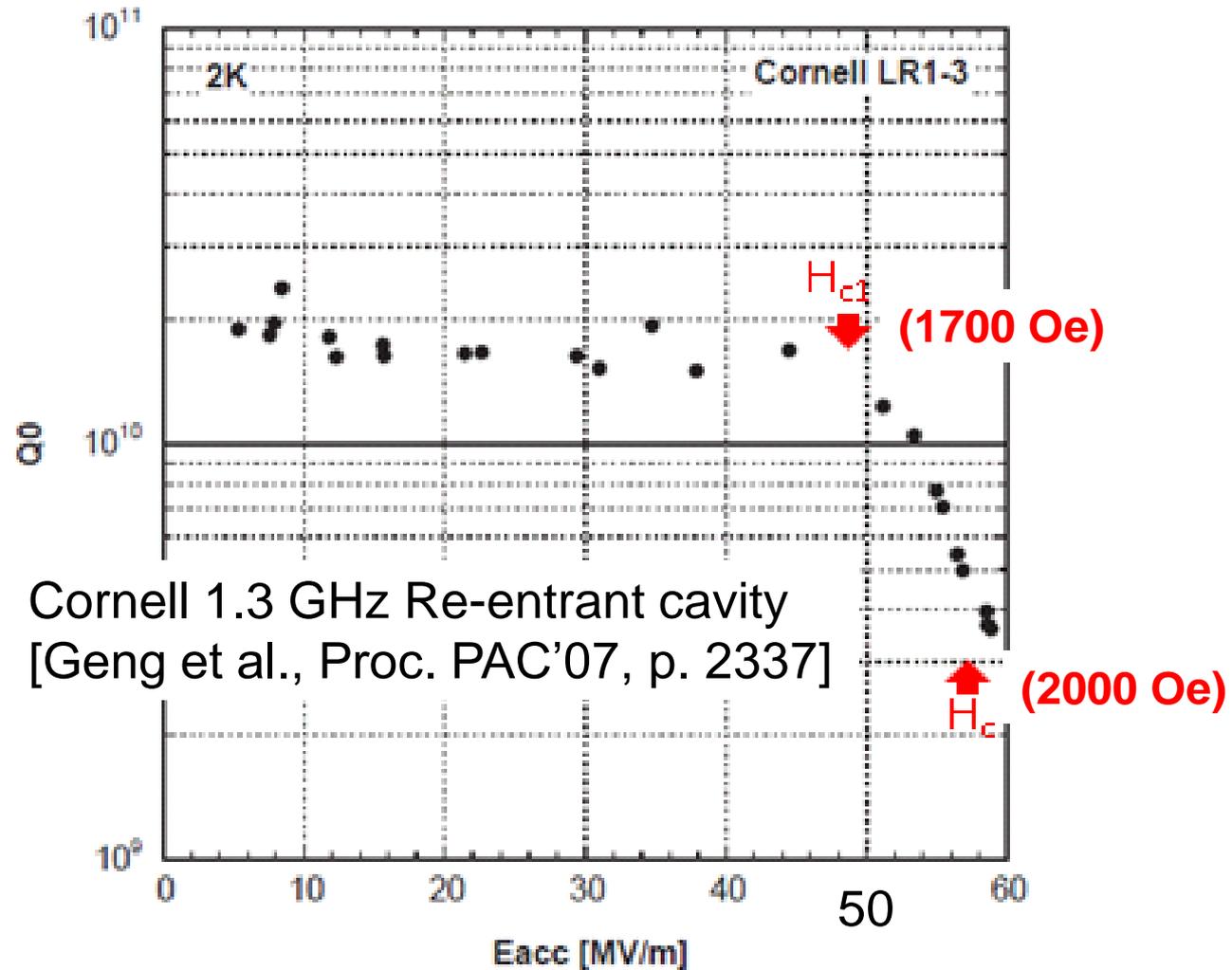
$$E_{peak} \cong 2 \cdot E_{acc}$$

$$\frac{B_{peak}}{E_{acc}} \cong \frac{4 \text{ mT}}{\text{MV/m}}$$

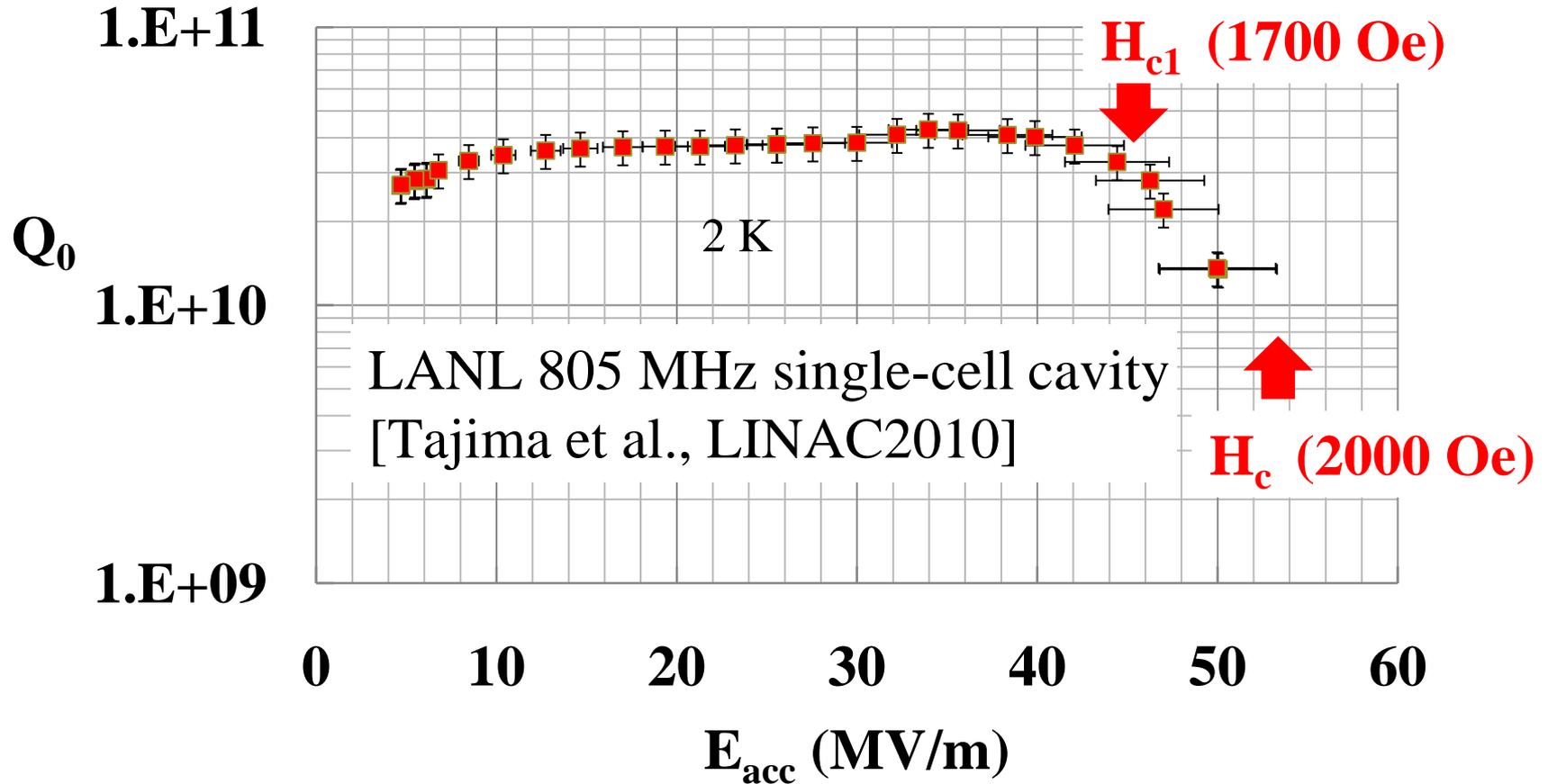
$$\text{Nb: } B_c \cong 200 \text{ mT} \\ (H_c \cong 2000 \text{ Oe})$$

$$\Rightarrow \text{max } E_{acc} \cong 50 \text{ MV/m}$$

H_{c1} sets practical limit of SRF technology

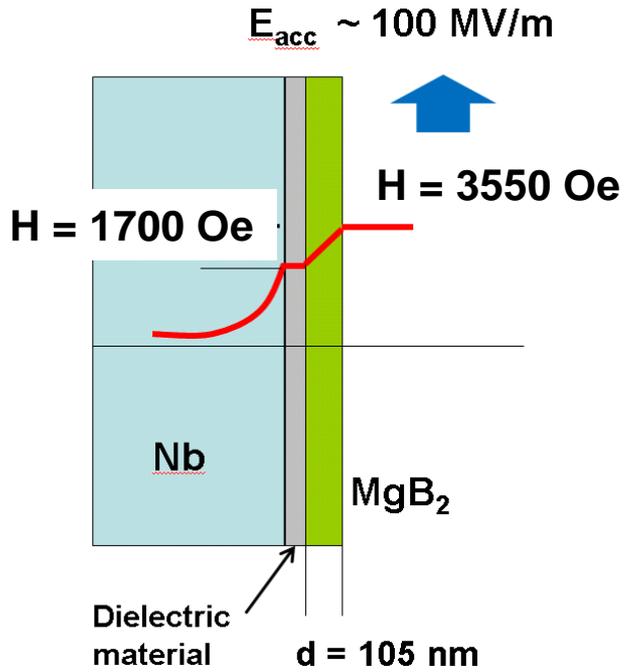


H_{c1} sets practical limit of SRF technology



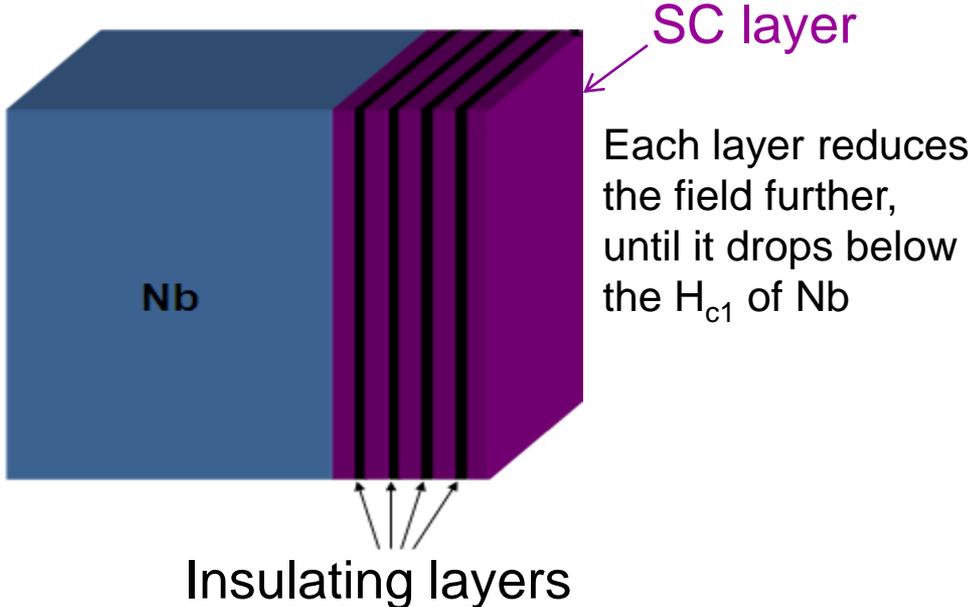
Gurevich's innovative idea: to overcome the fundamental limit of Nb cavities by using multilayers of superconducting/insulating thin films

Concept of field enhancement with a single layer of MgB₂



Problem: the thinner the layer, the smaller the field screening

Solution: multilayers to produce a "cascade" field screening effect



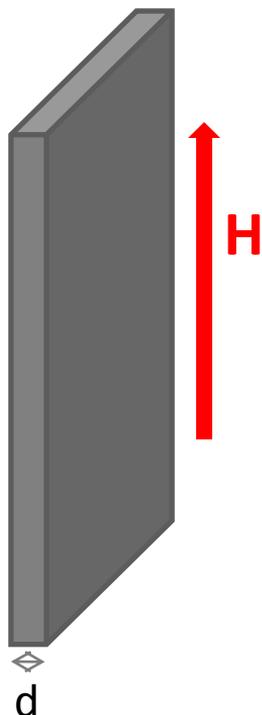
Gurevich only considered the limit $d \ll \lambda$
 Strongest H_{c1} enhancement, but

- many layers may be needed
- coating curved walls with uniform multilayers of very thin layers is challenging

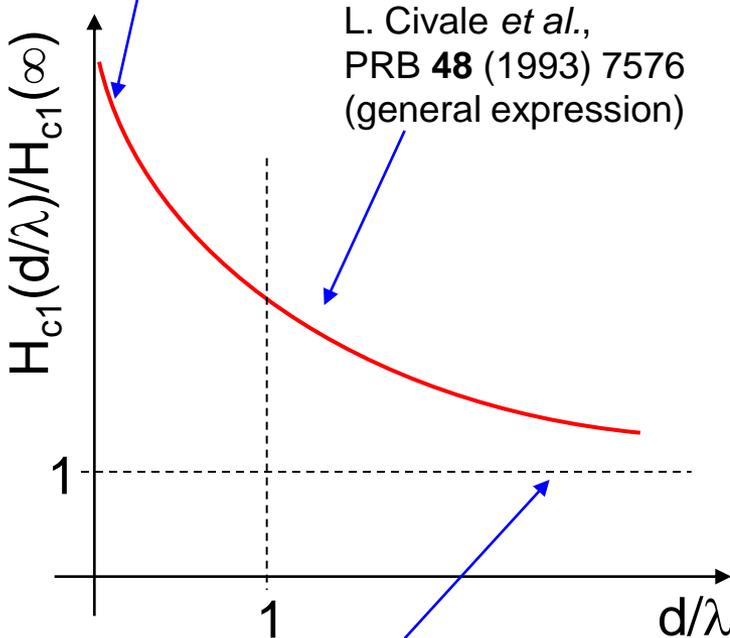
The key of Gurevich's proposal is that H_{c1} in parallel with the material surface can be increased using thin films if the thickness $d \sim \lambda$ (penetration depth) or thinner

[Gurevich, APL **88** (2006) 012511]

Same as in the cavity



$$H_{c1} \approx \frac{2\Phi_0}{\pi d^2} \ln \frac{d}{\xi} \quad (d \ll \lambda) \quad \xi: \text{coherence length}$$

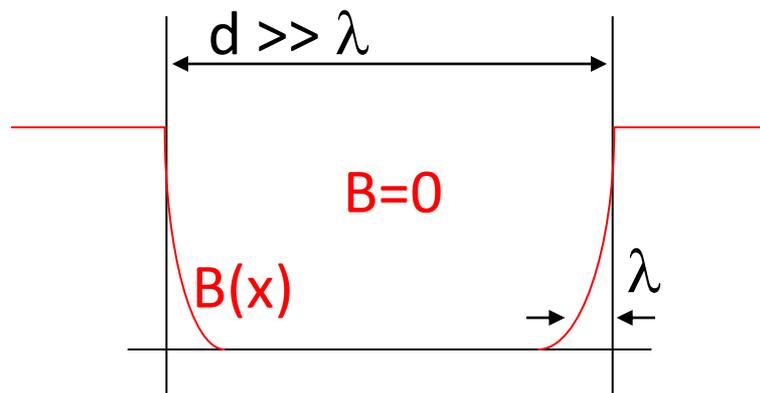
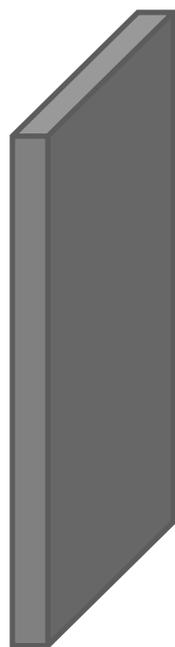


$$H_{c1} = \frac{\Phi_0}{4\pi\lambda^2} \ln \kappa \quad (d \gg \lambda)$$

$$\kappa = \frac{\lambda}{\xi}$$

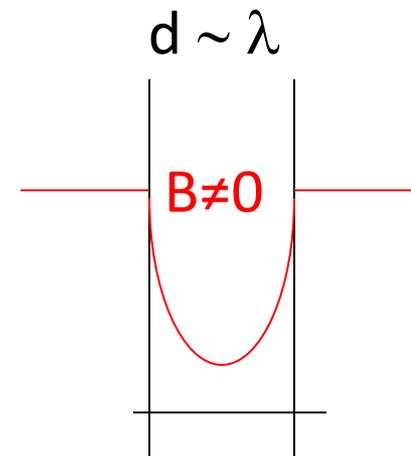
The walls of a superconducting cavity must remain free of vortices. If not: RF field \Rightarrow vortex oscillations \Rightarrow dissipation \Rightarrow drastic Q decrease

Superconducting film with $H//$ surface



Energy cost of expelling field: $\propto H$
 Energy of a vortex: H independent
 H_{c1} : vortex nucleation becomes thermodynamically favorable

Cavities must operate below H_{c1}

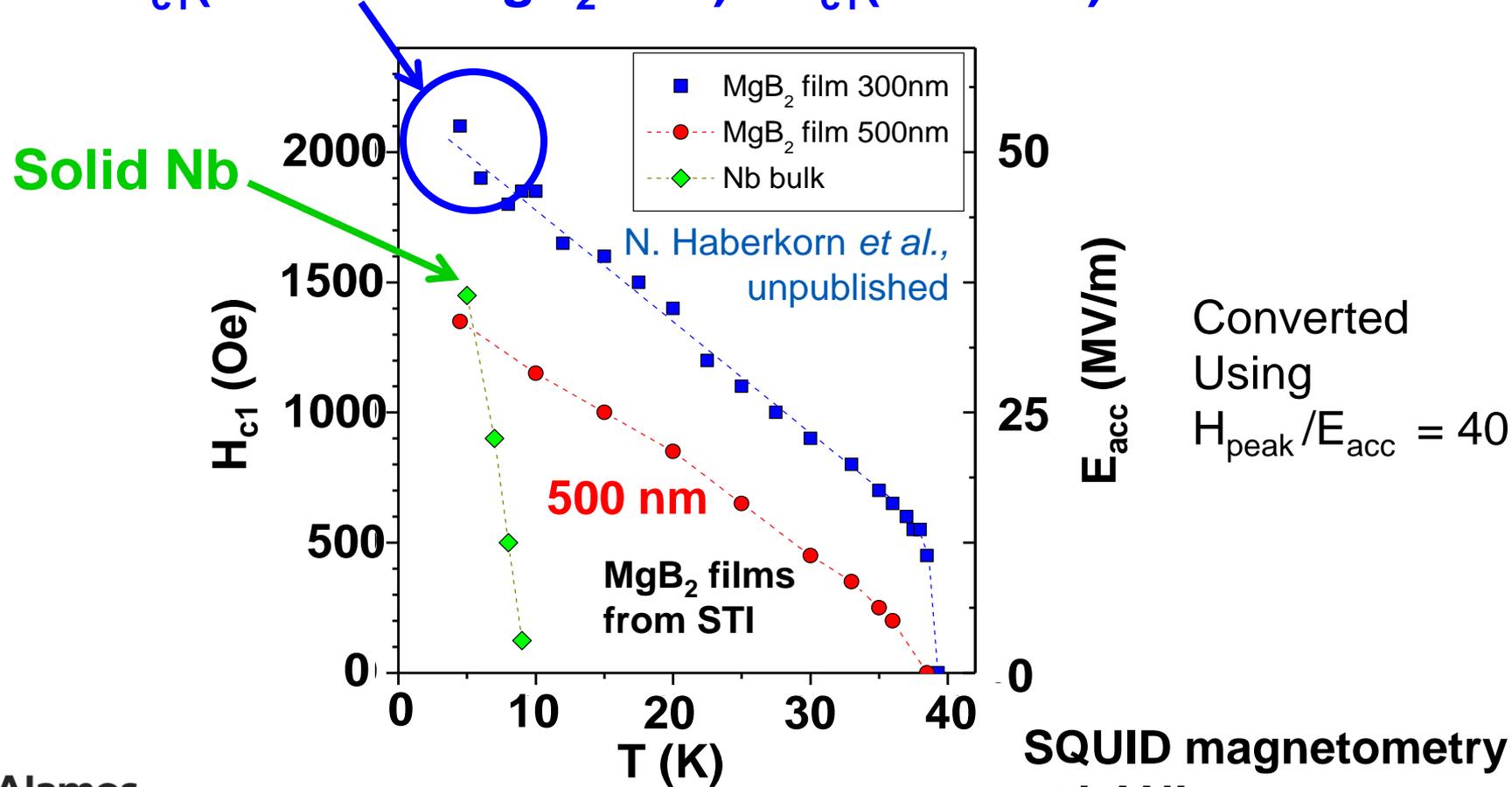


Cost of expelling field decreases
 H_{c1} increases (thermodynamics)

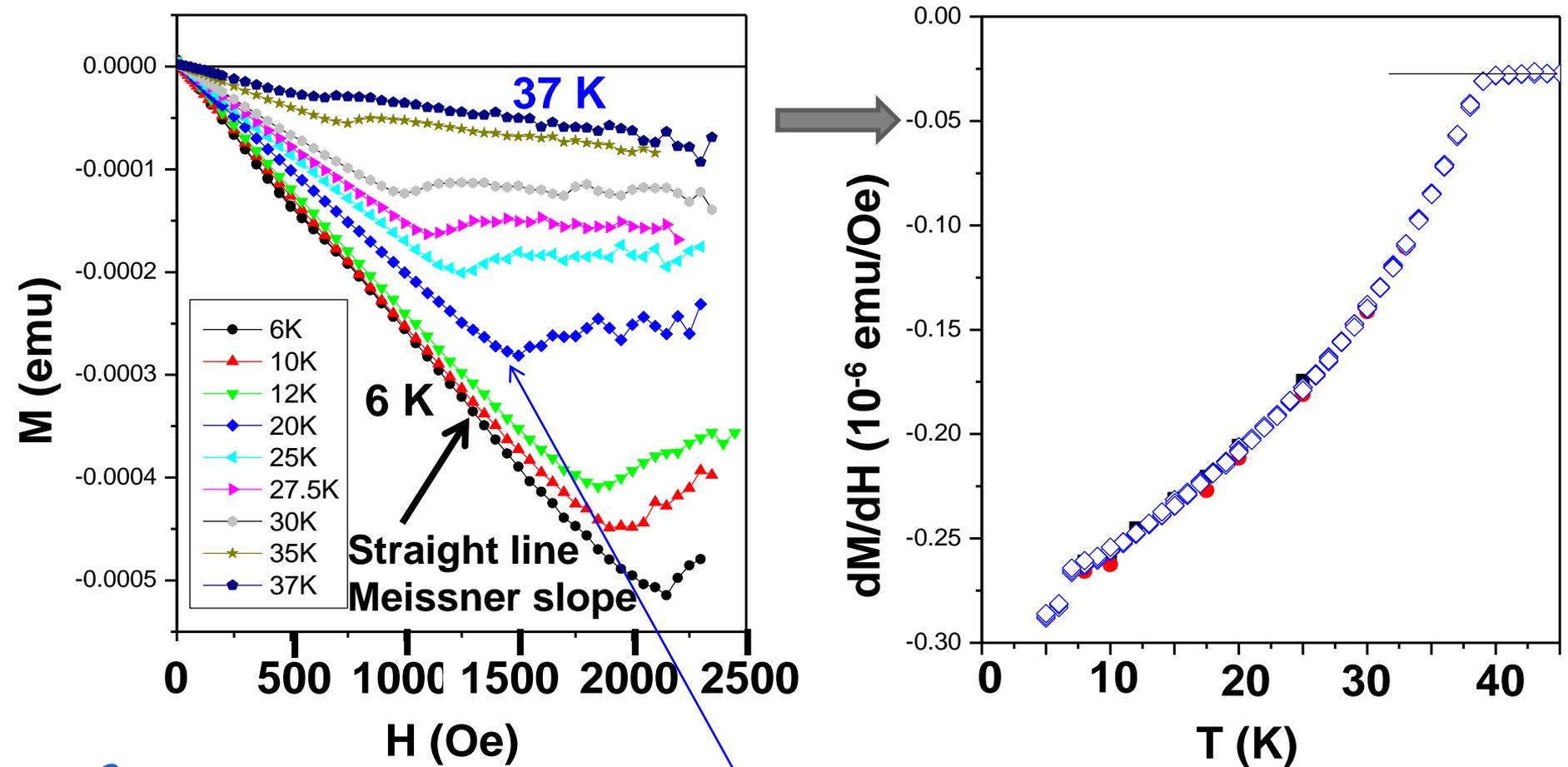
Possibility: coat the inside of the cavity with a superconducting thin film

H_{c1} of 300 nm MgB_2 film shows higher H_{c1} than Nb by ~25 % !
 At 4.5 K, the lowest measured temperature, $H_{c1} > 2000$ Oe

$H_{c1}(\sim 300 \text{ nm } MgB_2 \text{ film}) > H_{c1}(\text{bulk Nb})$

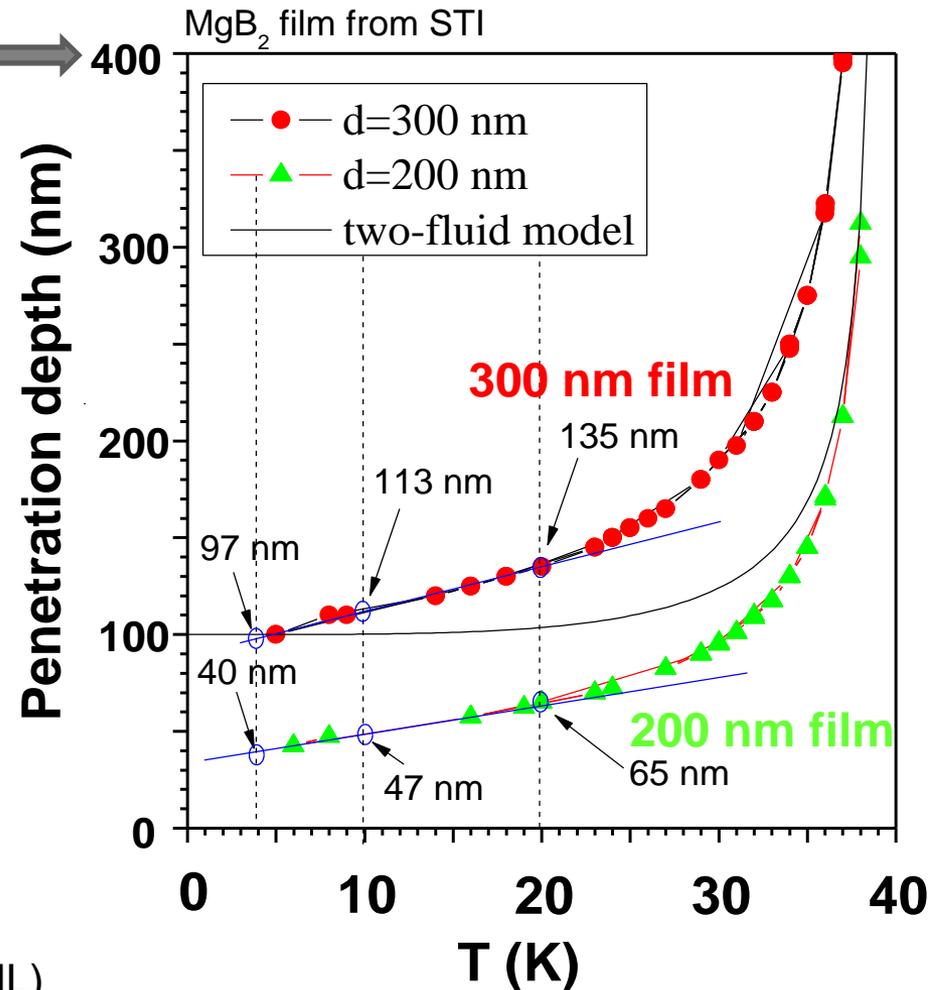
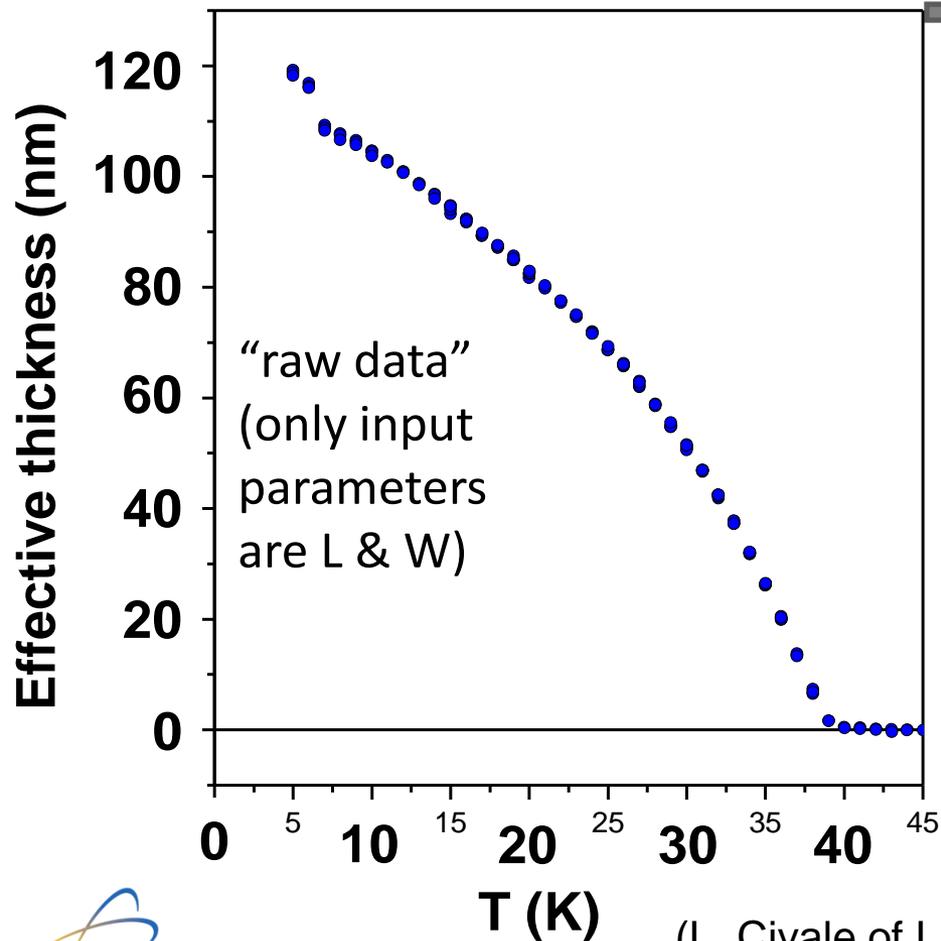


Preliminary results of 200 nm MgB₂ film: SQUID magnetometry (L. Civale of LANL)



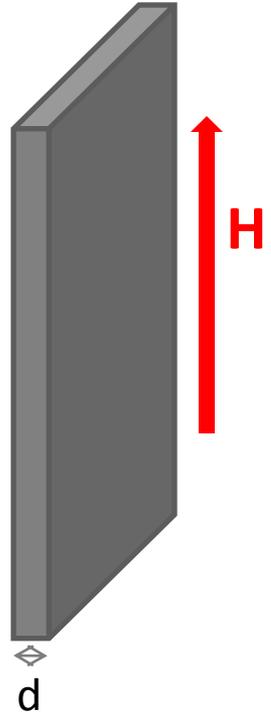
Point where a large number of vortices start to enter

Penetration depth increases with higher temperature! This causes the reduction of effective thickness!!



Magnetization measurements for <100 nm films have been difficult. We are considering a new method to detect field of vortex penetration into very thin films & multilayers based on ac transport techniques

Standard method:
SQUID magnetometer to detect deviation from Meissner response



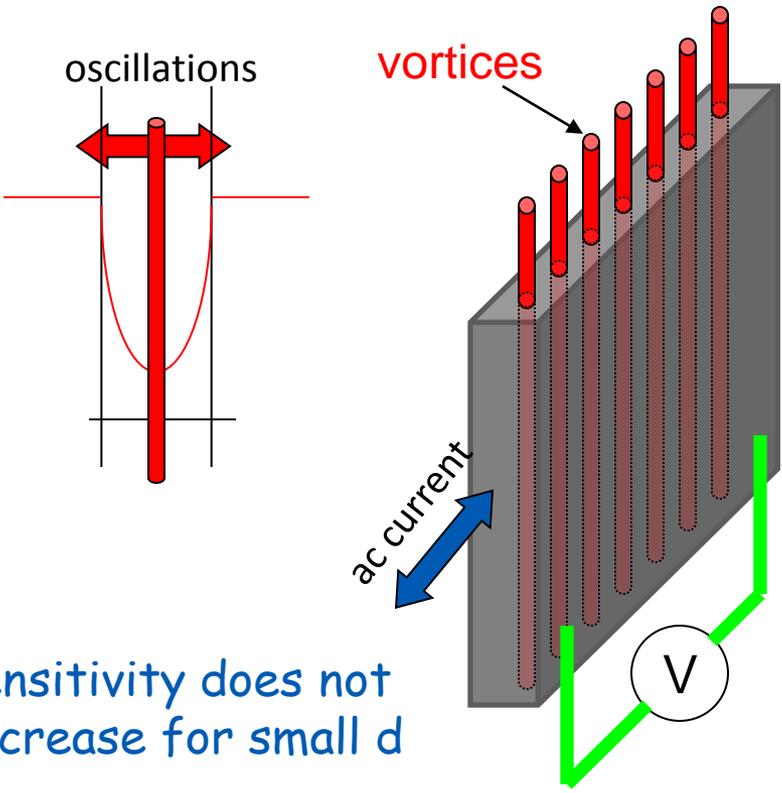
Meissner state:

$$m = -(H/4\pi)V_{\text{eff}} \propto d_{\text{eff}}$$

$$d_{\text{eff}} \sim d - 2\lambda \tanh(d/2\lambda)$$

Problem:
Very small signal.
Present resolution:
 $d \sim 100\text{nm}$ (for $\lambda \sim 100\text{nm}$)

Proposed alternative method:
Lock-in detection of voltage due to vortex oscillations driven by ac electric currents



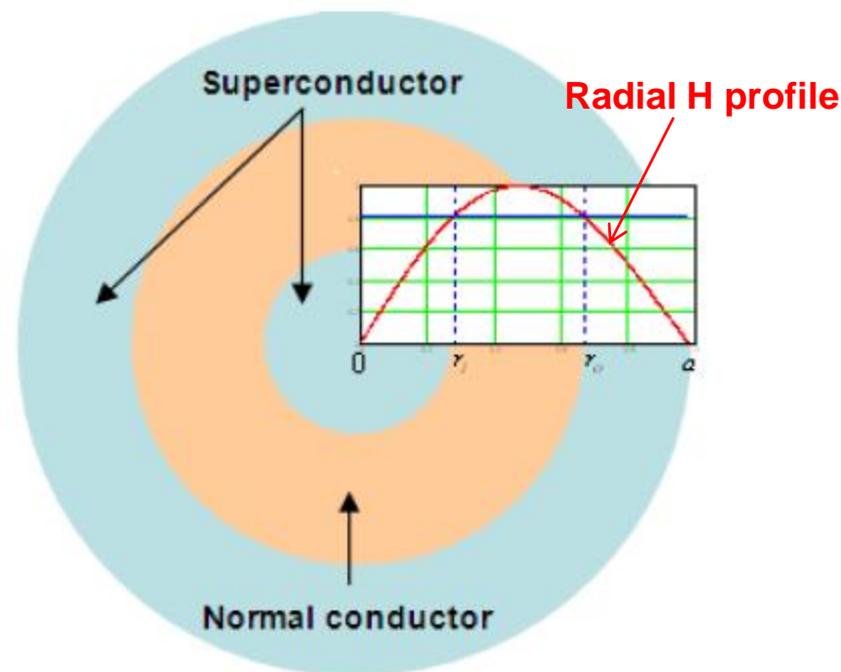
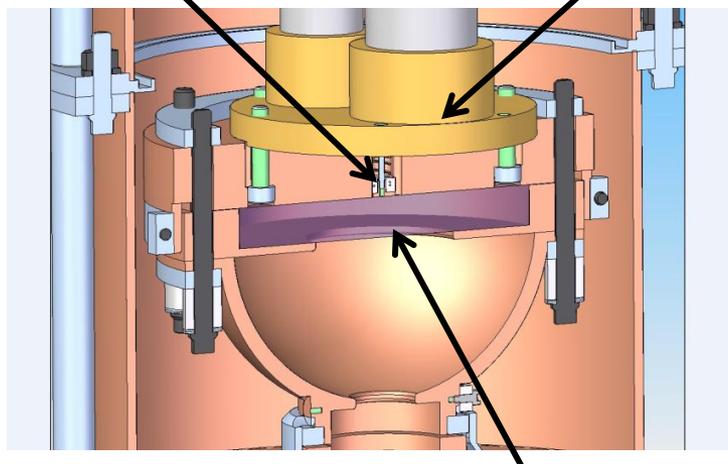
Sensitivity does not decrease for small d

RF measurements of 2-inch (~5 cm) diameter wafers (~1 mm thick) have been carried out at SLAC using 11.4 GHz pulsed power (~1.6 μ s) [J. Guo, S. Tantawi et al.]

Hemi-spherical TE_{013} mode cavity with magnetic fields in parallel with the sample surface

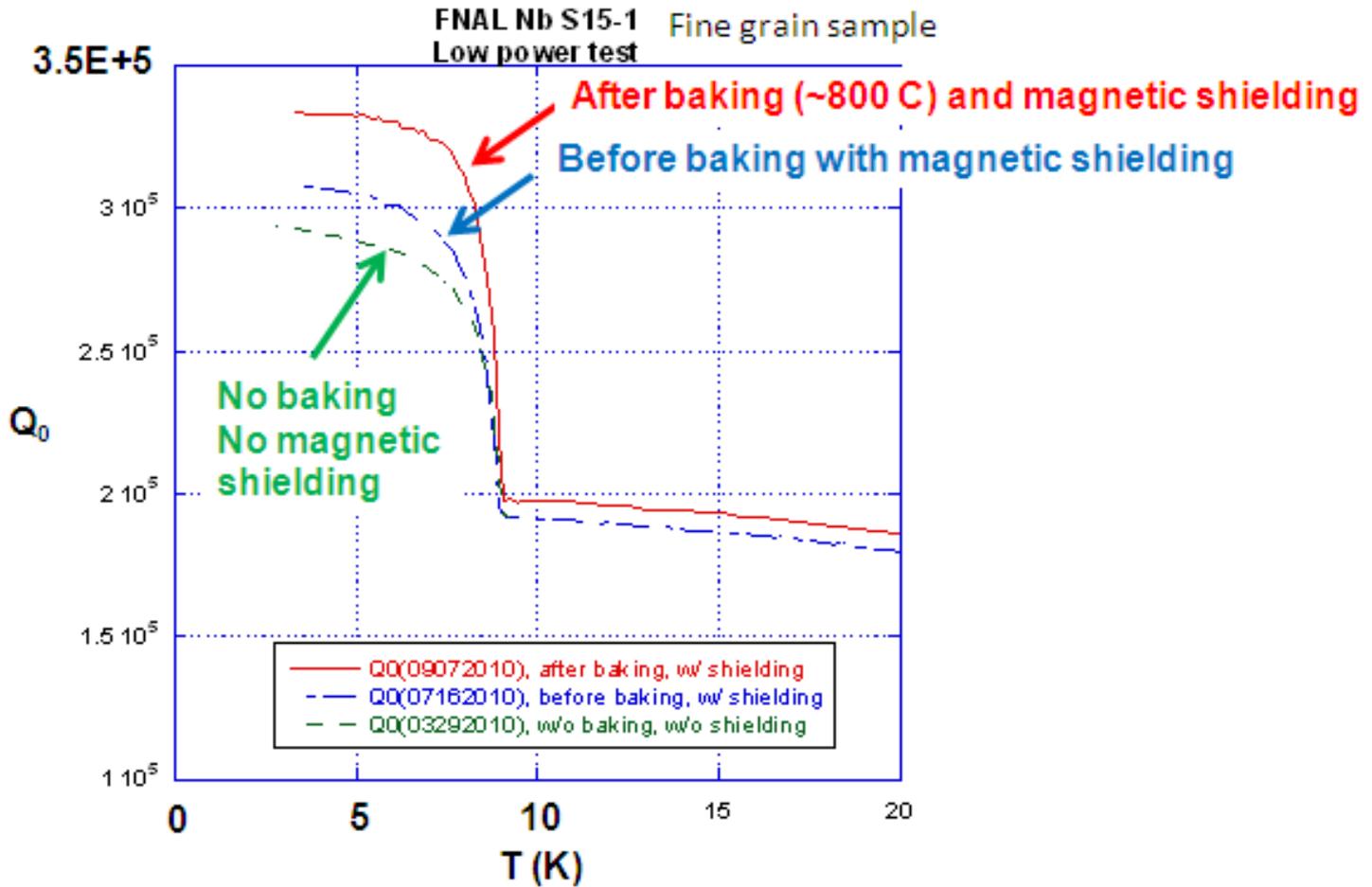
Typical distribution of superconducting and normal-conducting regions after quench

Temperature sensor Cold head

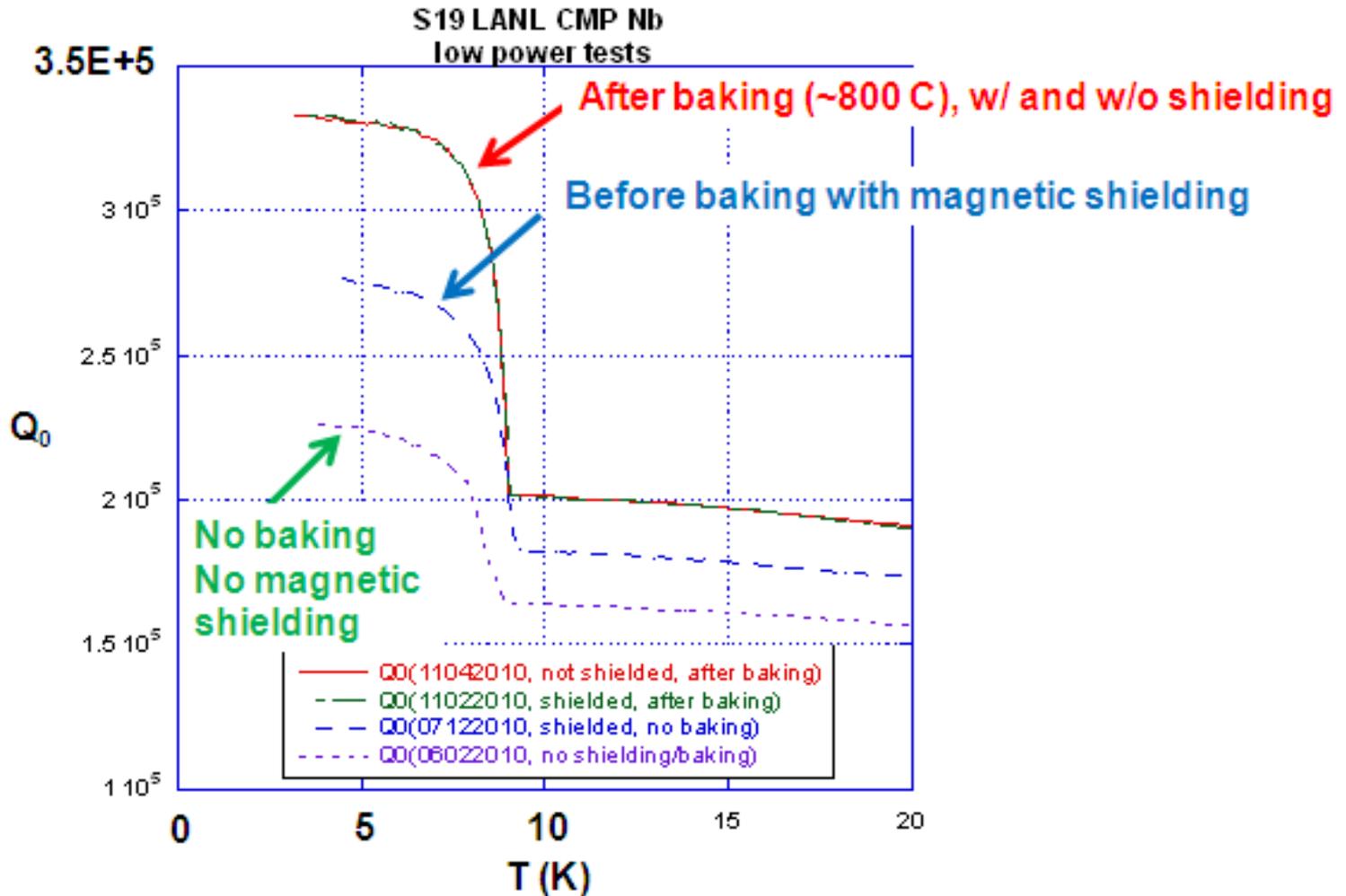


Sample: <1.5 mm thick

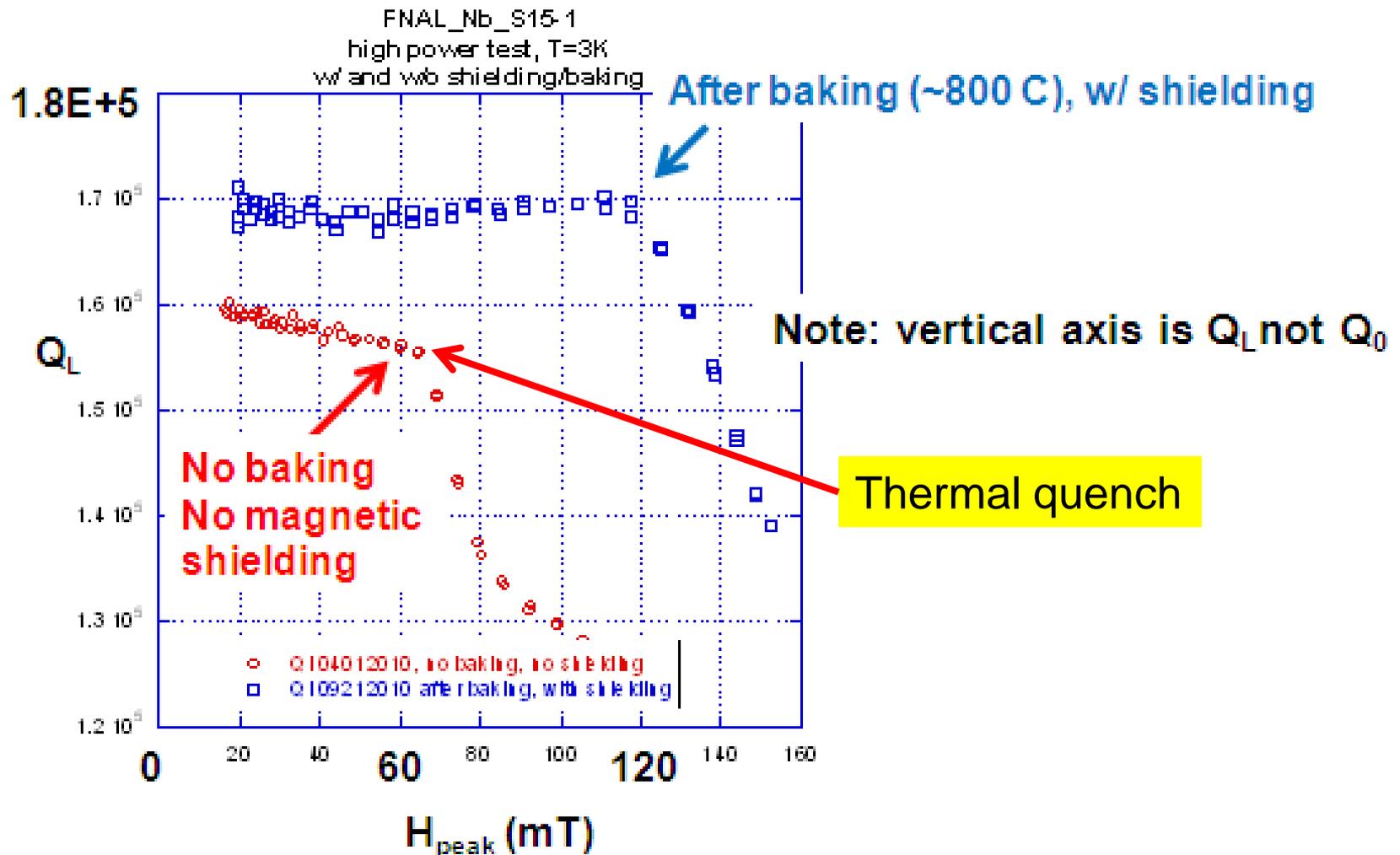
Some results from Nb samples have shown that surface condition affects the surface resistance (R_s) and quench field [J. Guo et al., poster TUP102 in this conference]



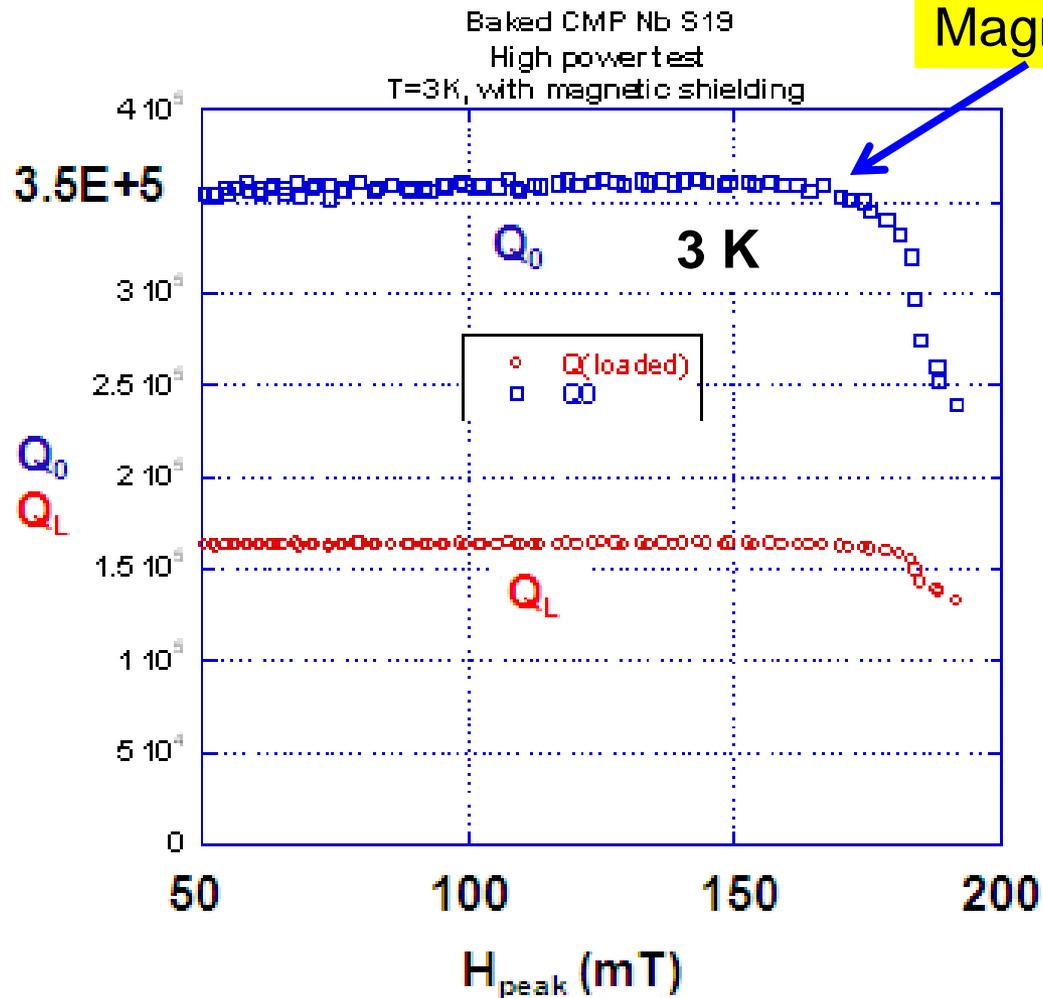
Q_0 vs. T of LANL single-grain sample, polished to $R_a < 1$ nm



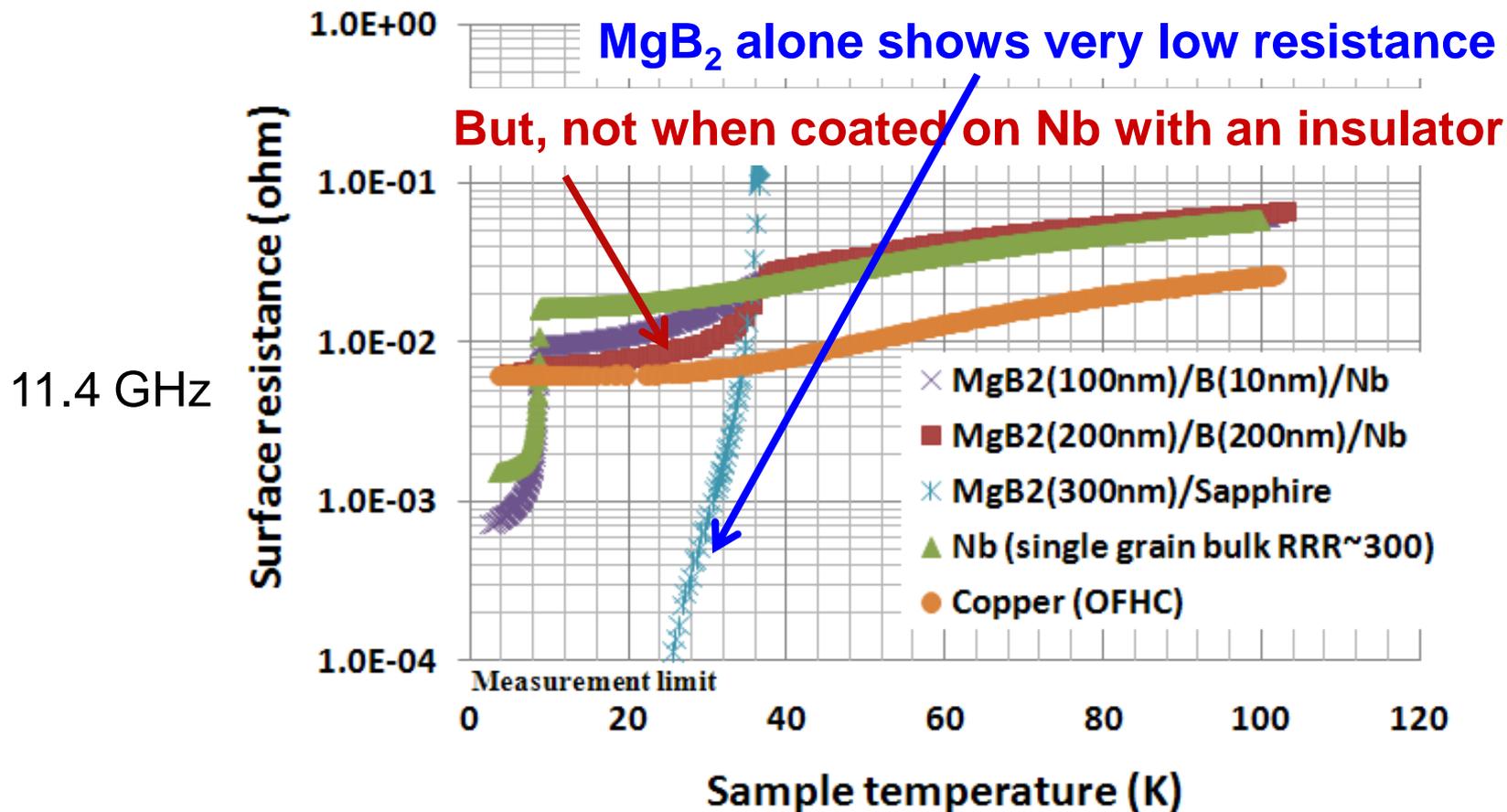
Q_L vs. H_{peak} of a FNAL fine-grain sample, indicating thermal quench due to high surface resistance



A LANL single-grain, polished and baked sample, has shown the highest quenching field (170-180 mT) so far

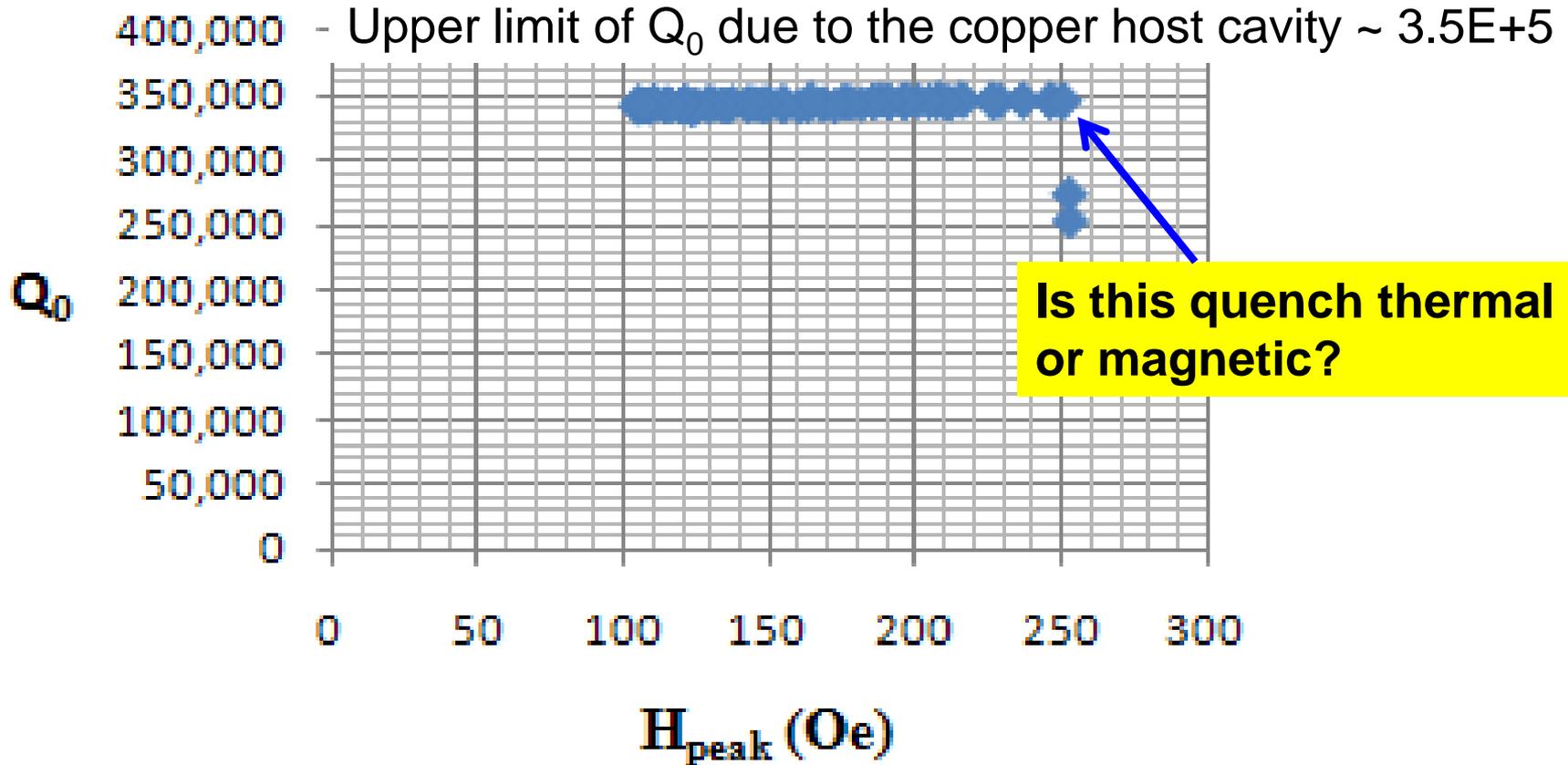


So, what about MgB_2 ?



300 nm MgB₂ films have shown low quenching field (250 Oe) at SLAC tests, which is puzzling, considering H_{c1} >2000 Oe from DC magnetization measurements

MgB₂(300nm)/Sapphire (430μm)



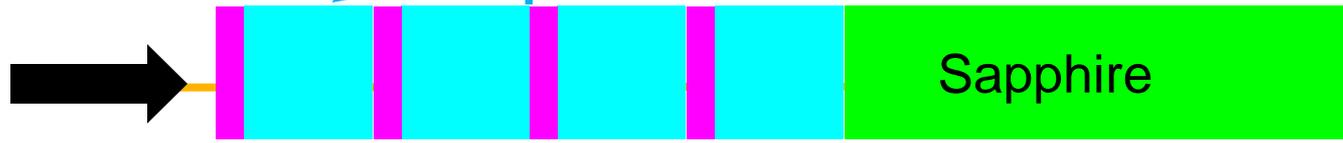
Issues on coating

- Degradation of Nb surface due to decomposition of stable natural Nb_2O_5 layer into a thick lossy NbO_x layer during coating processes at elevated temperatures (e.g., ALD Alumina at 300-345 °C and reactive co-evaporation MgB_2 at 550 °C)
- Inter-diffusion of elements (e.g., O, Al, Mg, etc.) that degrade the quality of MgB_2 and increase RF losses

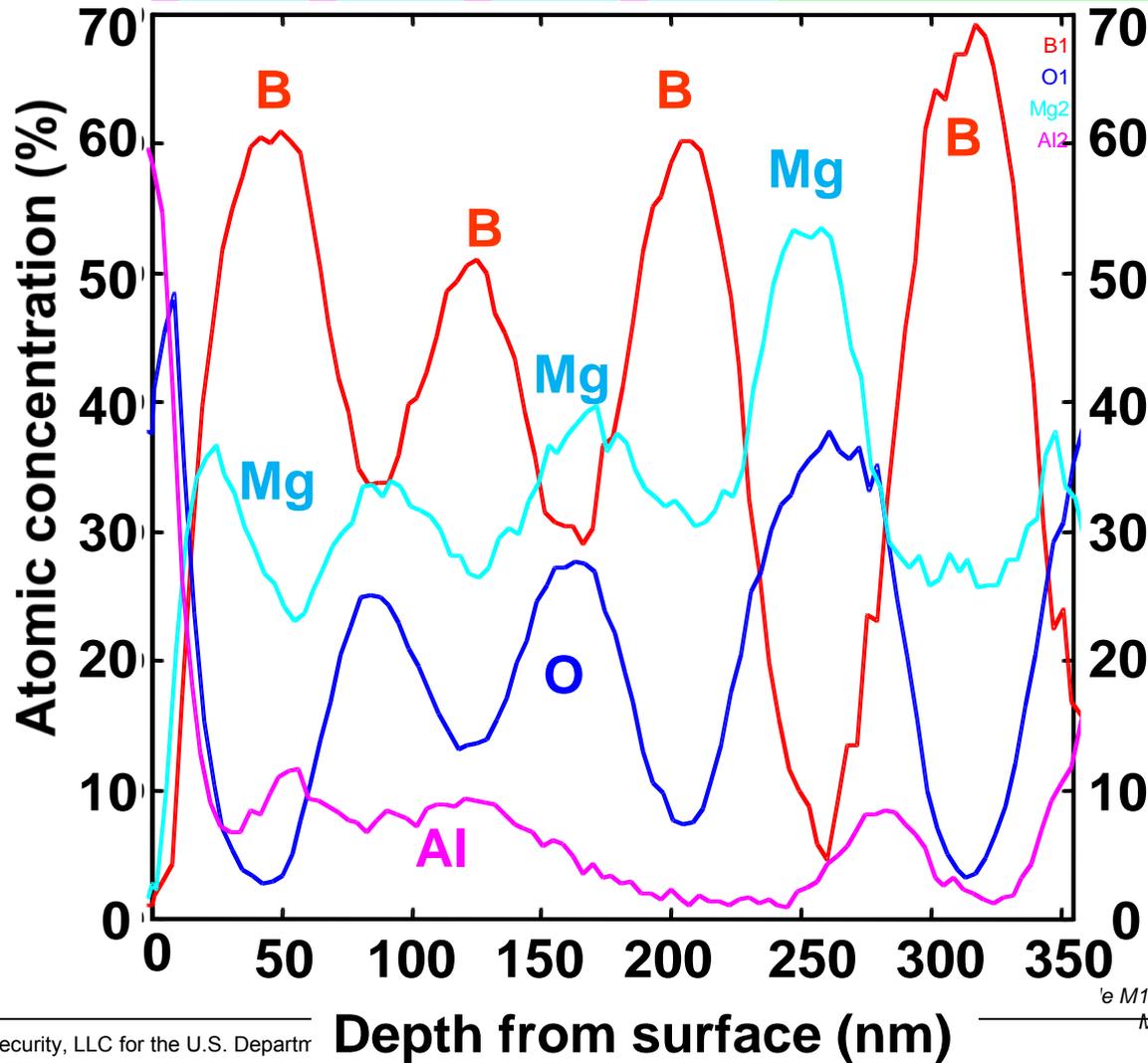
Inter-diffusion is a problem

Alumina (10nm) x 4 with Atomic Layer Deposition at 345 °C
MgB₂ (50 nm) x 4 with reactive co-evaporation at 550 °C

Intended structure



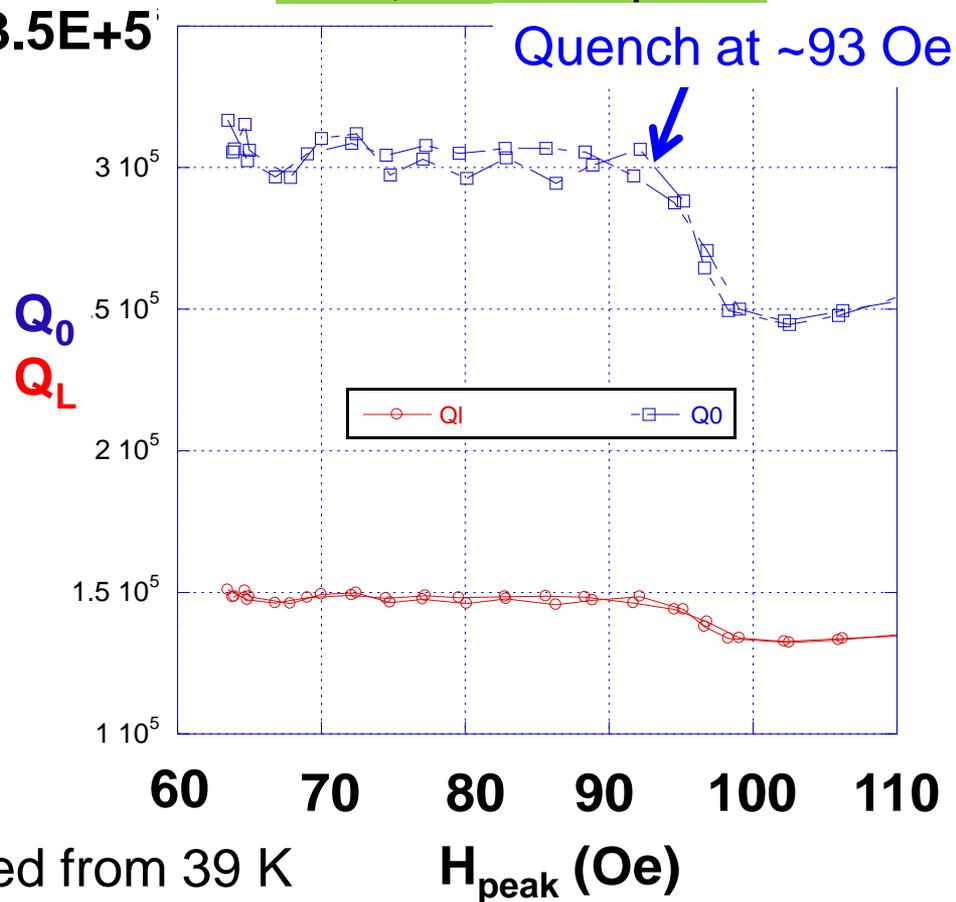
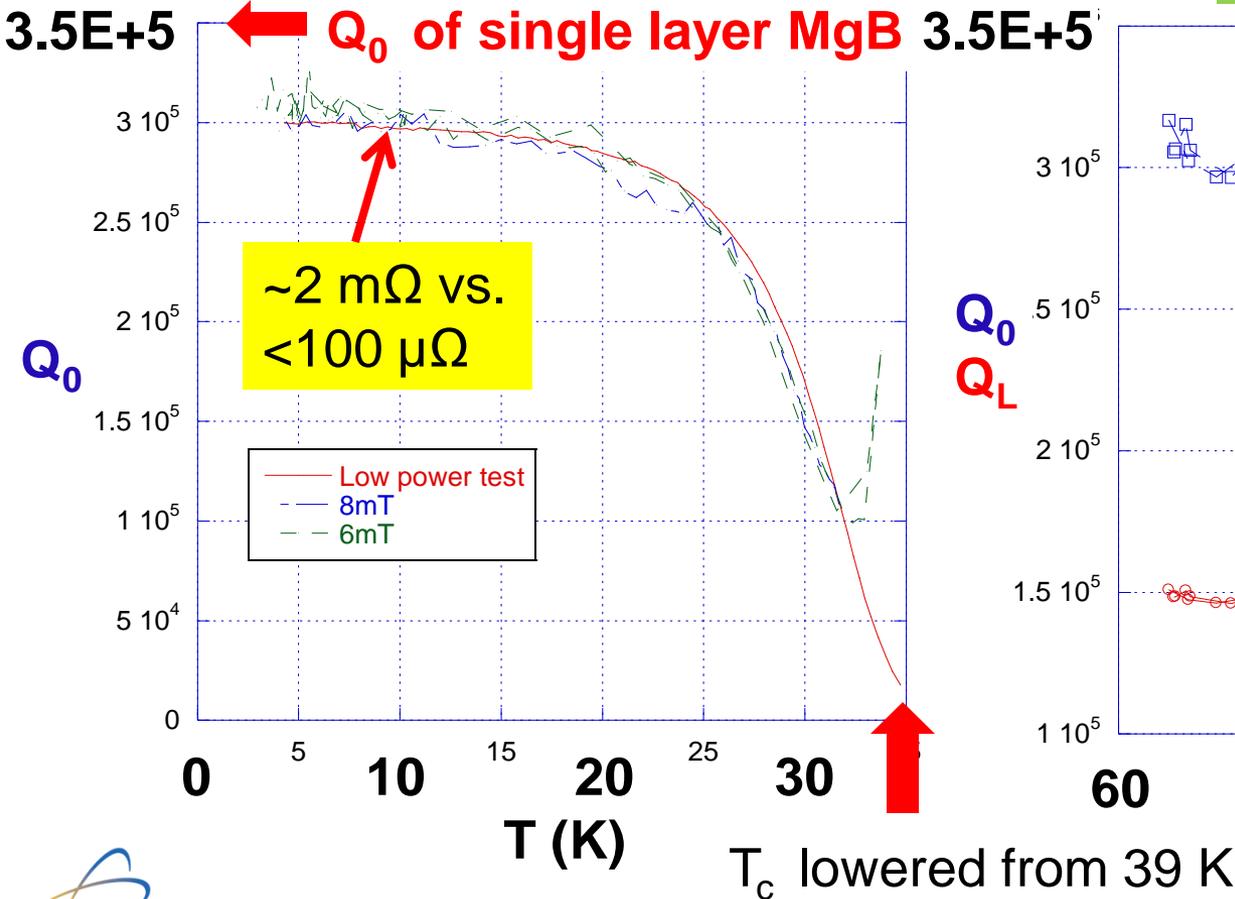
Actual structure



SLAC test results of [Alumina(10nm)/MgB₂(50nm)]x4/sapphire structure showed degradation of MgB₂ and quench field

Q₀ vs. T at low power

Q₀, Q_L vs. H_{peak}



Conclusion

- H_{c1} , a practical limit of SRF cavities, can be increased by thin superconductor films. A >25 % higher H_{c1} (>2000 Oe) than bulk Nb with ≤ 300 nm MgB_2 films at 4.5 K was demonstrated. Found that effective thickness must be considered for a layered structure!
- High-power RF tests at SLAC have shown low quench field of 250 Oe with 300 nm MgB_2 films, which needs to be understood. (>300 Oe has been reported elsewhere.)
- Preventing the increase of RF losses due to the degradation of Nb surface and coated superconductor will be the next step of development.

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Thanks for your attention!